Supplemental Material for 'Strong spin-orbit interaction and g-factor renormalization of hole spins in Ge/Si nanowire quantum dots"

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EXTENDED DATA SETS

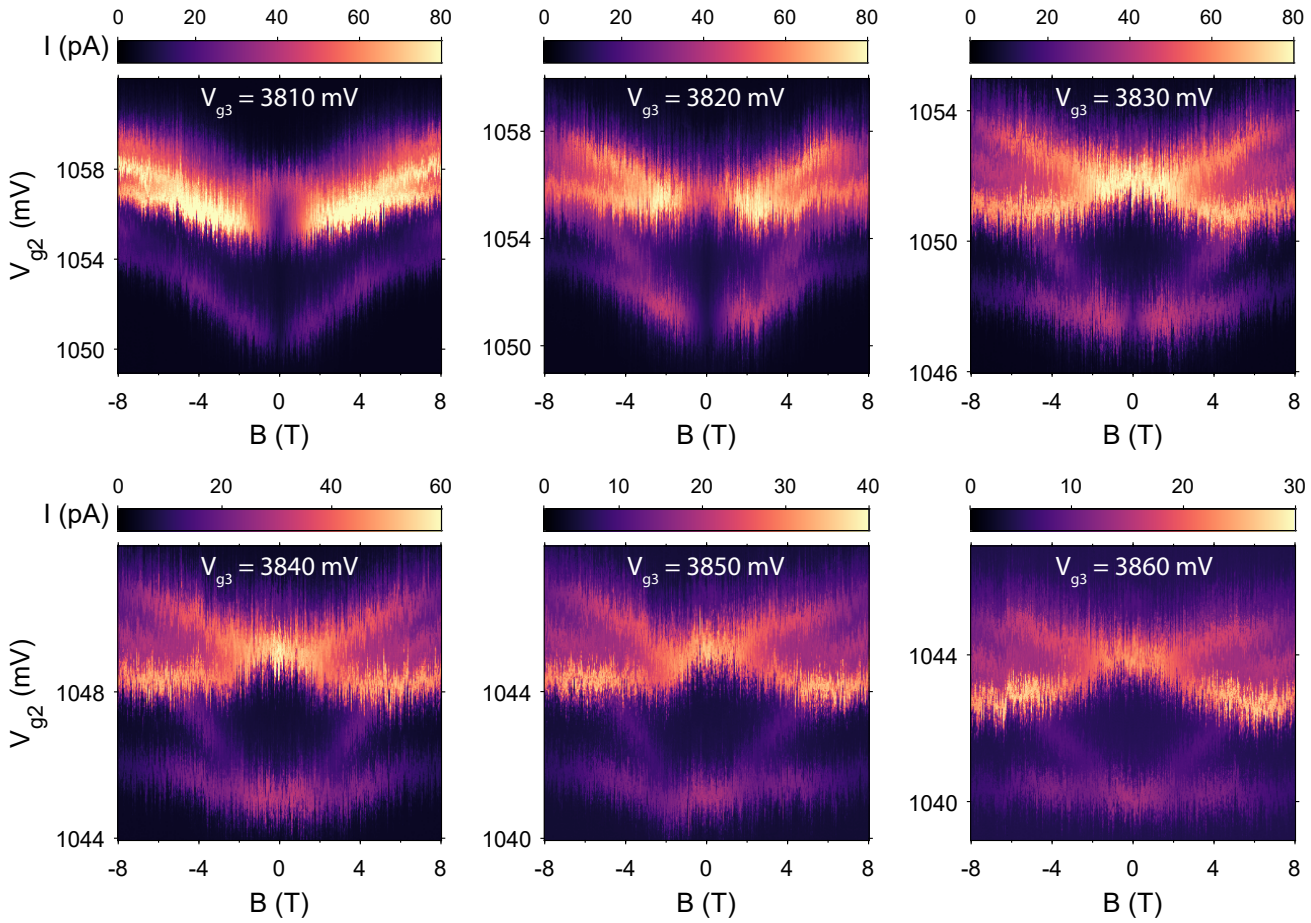

Figure S1. Extended data sets over full range of detuning, for values of V_{g3} as indicated in each plot. Here, V_{g4} is swept simultaneously with V_{g2}, along the detuning arrow shown in Fig. 1(c) of the main text.

ZOOM-IN OF FIG. 4(A)

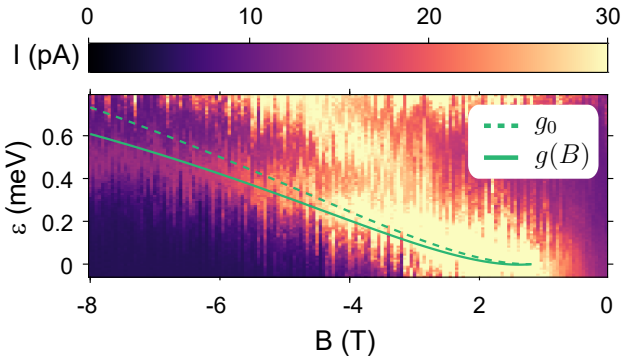

Figure S2. Zoom-in of Fig. 4(a) of the main text, highlighting the role of g-factor renormalization at high magnetic field. Green curves are identical to those in main curves, corresponding to $\varepsilon_{\pm}(B)$ with (solid) and without (dashed) taking into account the g-factor renormalization with magnetic field given by Eq. 2.